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Guidance of Passive EDA models

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1. SI Modeling Issues in Passive Devices

2. Guidance of Passive EDA models

3. Summary

We had studied interconnect model in JEITA EDA-WG last year and reported that simulation and measurements results were nearly good match. (The EDA models were provided by component manufacturer, but not specially prepared models.)



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The EDA models were described by S-parameters and equivalent circuit. It had no problem with the equivalent circuit models but the S-parameters had some problem as below.

- 1. No DC point of S-parameters.
- 2. Bandwidth limitation. (300KHz-8.5GHz)
- 3. Each bandwidth of the EDA models might not be the same.
- 4. Each number of points of S-parameters might not be the same.
- 5. It is uncertain how S-parameters are measured.

In the EDA –WG, We discussed various problems, and concluded it as follows.

- 1. Must include DC point of S-parameters .
- 2. Consider upper limitation of S-parameters for rise time.
- 3. Not able to standardize bandwidth of S-parameters of each EDA models in all manufacturer.
- 4. Not able to standardize number of points of S-parameters each EDA models as well.
- 5. Some manufacturers have disclosed measuring method to the public on Web.

- 1. The method of measuring of DC point of S-parameters is disclosed to the public.
- 2. To do transient analysis, it is necessary to consider minimum bandwidth and number of points of S-parameters.
- 3. The method of measuring the EDA models is disclosed to the public.
- 4. The usage of the EDA models is disclosed to the public.

Measuring method of DC point of S-parameters



Device Under Test



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S-parameters of TDR vs. VNA (DC-20GHz)



S-parameters of TDR vs. VNA(DC-100MHz)











S-parameters of VAN vs. TDR (DC-20GHz)





- 1. The problem of the EDA model was shown.
- 2. The problem of the EDA model was discussed.
- 3. The method of measuring of DC point of S-parameters was shown.

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